

- Positive output voltage regulator
- Lower operating current
- Higher output voltage regulation capability

■OUTLINE

SCI7810Y series a fixed type voltage regulator developed utilizing CMOS silicon gate process. It is configured with a reference circuit, differential amplifier, output control transistor and voltage setting resistor of high accuracy and low operating current.

Output voltage is fixed in IC. This series supports a variety of output voltages.

FEATURES

Low operating current

 Smaller temperature difference between output and input voltages

Smaller output voltage temperature coefficient

Larger operating voltage range

Higher output voltage regulation capability

Package

Typically, 1.5 μ A (V_{DD} = 5.0V)

Typically 0.17V ($I_O = 10mA$, $V_{OUT} = 5.0V$)

Typically, -100ppm/°C

15V maximum

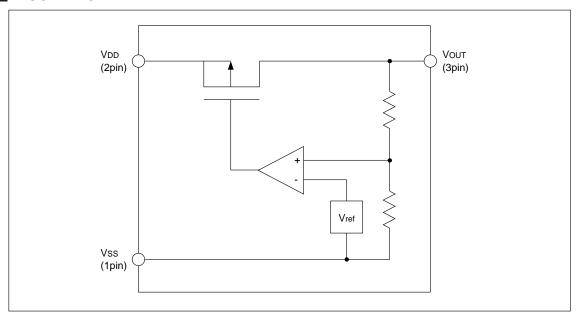
 $\pm 2.0\%$ (V_{DD}=7.0V, I_P=10mA, V_{OUT} = 5.0V, Ta=25°C)

SOT89-3pin

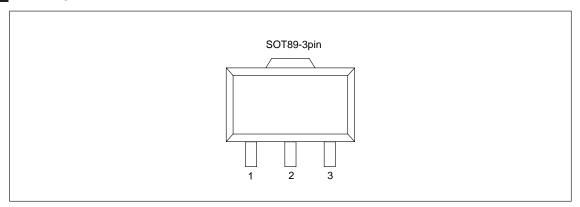
MODEL TYPES

	Input voltage	Output voltage (V)		Output current (Max.)	Operating current		
Model names	(V)	Min.	Тур.	Max.	(mA) ` ´	(μA)	
SCI7810YHA		1.45	1.50	1.55	10 at VI = 3V		
SCI7810YGA		1.75	1.80	1.85	10 at VI = 3V		
SCI7810YFA		2.15	2.20	2.25	10 at VI = 3V		
SCI7810YLA		2.53	2.60	2.67	30 at VI = 5V		
SCI7810YRA		2.73	2.80	2.87	30 at VI = 5V		
SCI7810YDA		2.93	3.00	3.07	30 at VI = 5V		
SCI7810YCA	15	3.13	3.20	3.27	30 at VI = 5V	1.5	
SCI7810YTA		3.23	3.30	3.37	30 at VI = 5V	1.5	
SCI7810YNA		3.43	3.50	3.57	30 at VI = 5V		
SCI7810YKA		3.80	3.90	4.00	40 at V = 6V		
SCI7810YPA		3.90	4.00	4.10	40 at VI = 6V		
SCI7810YMA		4.40	4.50	4.60	40 at VI = 6V		
SCI7810YBA		4.90	5.00	5.10	50 at VI = 7V		
SCI7810YAA		5.75	6.00	6.25	50 at VI = 8V		

■BLOCK DIAGRAM



PIN DIAGRAM



PIN DESCRIPTION

Pin No.	Pin names	Function
1	V _{SS}	Input voltage pin (negative side)
2	V_{DD}	Input voltage pin (positive side)
3	V _{OUT}	Output voltage pin

■ ABSOLUTE MAXIMUM RATINGS

Items	Symbols	Rating	Unit	
Input voltage	V _{DD} -V _{SS}	18	V	
Output voltage	Vo	V_{DD} + 0.3 to V_{SS} -0.3		
Output current	Io	100	mA	
Allowable loss	P _D	200	mW	
Operating temperature	T _{opr}	-30 to +85		
Storage ambient	т	-65 to +150	°C	
temperature	T _{stg}	-03 to +130		
Soldering time	T _{sol}	260°C		
Soldering temperature		10 sec. (at lead)	_	

ELECTRIC CHARACTERISTICS

●SCI7810Y_{AA}

(Except where otherwise specified, Ta=-30°C to +85°C)

Items	Symbols	Condition (VSS = 0.0V)	Min.	Тур.	Max.	Unit
Input voltage	Vı		_	_	15	V
Output voltage	Vo	VDD = 8.0V, IO = -10mA $Ta = 25^{\circ}C$	5.75	6.00	6.25	V
Operating current	ЮР	VDD = 6.0V to 15.0V No load	_	1.5	5.0	μΑ
Voltage difference between input and output voltages	VI–Vo	VOUT = 6.0V, IO = -10mA	_	0.16	0.32	V
Output voltage temperature characteristics	ΔVOUT VOUT		-300	-100	+100	ppm/°C
Input stability	dVo dVI•Vo	Ta = -30°C to +85°C (Same temperature condition) VDD = 7.0V to 15.0V IO = -10mA	_	0.1	_	%/ V
Load stability	ΔVο	Ta = -30°C to +85°C (Same temperature condition) VDD = 8.0V IO = -1mA to -50mA	_	50	_	mV
Supply voltage fluctuation elimination ratio	PSRR	$VDD = 8.0V, f_{in} = 50kHz$ $CL = 10 \mu F, IOUT = -10mA$	_	-40	_	dB

●SCI7810YBA

(Except where otherwise specified, Ta=-30°C to +85°C)

Items	Symbols	Condition (VSS = 0.0V)	Min.	Тур.	Max.	Unit
Input voltage	VI		_	_	15	V
Output voltage	Vo	VDD = 7.0V, IO = -10mA Ta = 25°C	4.90	5.00	5.10	V
Operating current	ЮР	VDD = 5.0V to 15.0V No load	-	1.5	5.0	μΑ
Voltage difference between input and output voltages	Vı-Vo	VOUT = 5.0V, IO = -10mA	_	0.17	0.34	V
Output voltage temperature characteristics	$\frac{\Delta V O U T}{V O U T}$		-300	-100	+100	ppm/°C
Input stability	dVo dV _{I*} Vo	Ta = -30°C to +85°C (Same temperature condition) VDD = 6.0V to 15.0V IO = -10mA	-	0.1	_	%/ V
Load stability	ΔVο	Ta = -30°C to +85°C (Same temperature condition) VDD = 7.0V IO = -1mA to -50mA	-	50	_	mV
Supply voltage fluctuation elimination ratio	PSRR	$VDD = 7.0V, f_{in} = 50kHz$ $CL = 10\mu F, IOUT = -10mA$	-	-40	_	dB

●SCI7810YKA

(Except where otherwise specified, Ta=-30°C to +85°C)

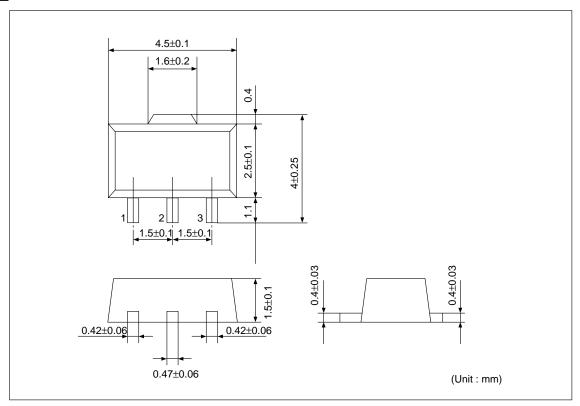
Items	Symbols	Condition (VSS = 0.0V)	Min.	Тур.	Max.	Unit
Input voltage	VI			_	15	V
Output voltage	Vo	VDD = 6.0V, IO = -10mA $Ta = 25^{\circ}C$	3.80	3.90	4.00	V
Operating current	ЮР	VDD = 3.9V to 15.0V No load	_	1.5	5.0	μΑ
Voltage difference between input and output voltages	Vı–Vo	VOUT = 3.9V, IO = -10mA		0.19	0.38	V
Output voltage temperature characteristics	ΔVOUT VOUT		-300	-100	+100	ppm/°C
Input stability	_dVo _dVı•Vo	Ta = -30°C to +85°C (Same temperature condition) VDD = 5.0V to 15.0V IO = -10mA	_	0.1	_	%/ V
Load stability	ΔVο	Ta = -30°C to +85°C (Same temperature condition) VDD = 6.0V IO = -1mA to -40mA	_	40	_	mV
Supply voltage fluctuation elimination ratio	PSRR	$VDD = 6.0V, f_{in} = 50kHz$ $CL = 10\mu F, IOUT = -10mA$	_	-40	_	dB

●SCI7810Y_{DA}

(Except where otherwise specified, Ta=-30°C to +85°C)

Items	Symbols	Condition (VSS = 0.0V)	Min.	Тур.	Max.	Unit
Input voltage	Vı		_	_	15	V
Output voltage	Vo	VDD = 5.0V, IO = -10mA Ta = 25°C	2.93	3.00	3.07	V
Operating current	lop	VDD = 3.0V to 15.0V No load	_	1.5	5.0	μΑ
Voltage difference between input and output voltages	VI–Vo	VOUT = 3.0V, IO = -10mA	_	0.23	0.46	V
Output voltage temperature characteristics	ΔVOUT VOUT		-300	-100	+100	ppm/°C
Input stability	dVo dVI•Vo	Ta = -30°C to +85°C (Same temperature condition) VDD = 4.0V to 15.0V IO = -10mA	_	0.1	_	%/ V
Load stability	ΔVο	Ta = -30°C to +85°C (Same temperature condition) VDD = 5.0V IO = -1mA to -30mA	_	30	_	mV
Supply voltage fluctuation elimination ratio	PSRR	$VDD = 5.0V, f_{in} = 50kHz$ $CL = 10\mu F, IOUT = -10mA$	_	-40	_	dB

OVERALL DIMENSION DIAGRAM



Note:Dimensions are subject to change for the product innovation.

NOTICE:

No part of this material may be reproduced or duplicated in any form or by any means without the written permission of Seiko Epson. Seiko Epson reserves the right to make changes to this material without notice. Seiko Epson does not assume any liability of any kind arising out of any inaccuracies contained in this material or due to its application or use in any product or circuit and, further, there is no representation that this material is applicable to products requiring high level reliability, such as, medical products. Moreover, no license to any intellectual property rights is granted by implication or otherwise, and there is no representation or warranty that anything made in accordance with this material will be free from any patent or copyright infringement of a third party. This material or portions thereof may contain technology or the subject relating to strategic products under the control of the Foreign Exchange and Foreign Trade Law of Japan and may require an export license from the Ministry of International Trade and Industry or other approval from another government agency.

© Seiko Epson Corporation 2000 All right reserved.

All other product names mentioned herein are trademarks and/or registered trademarks of their respective companies.

SEIKO EPSON CORPORATION

ELECTRONIC DEVICES MARKETING DIVISION

IC Marketing & Engineering Group

ED International Marketing Department I (Europe & U.S.A.) 421-8, Hino, Hino-shi, Tokyo 191-8501, JAPAN Phone: +81-(0)42-587-5812 FAX: +81-(0)42-587-5564

ED International Marketing Department II (Asia) 421-8, Hino, Hino-shi, Tokyo 191-8501, JAPAN

Phone: +81-(0)42-587-5814 FAX: +81-(0)42-587-5110

■ EPSON Electronic Devices Website http://www.epson.co.jp/device/



First issue November, 1996 Printed February, 2000 in Japan T